40V +175°C P-CHANNEL ENHANCEMENT MODE MOSFET
PowerDI®3333-8

Product Summary

BV_{DSS}	$R_{DS(ON)}$ Max	I_D Max T_C = +25°C
-40V	25mΩ @ V_{GS} = -10V	-40A
	45mΩ @ V_{GS} = -4.5V	-30A

Features and Benefits

- Rated to +175°C—Ideal for High Ambient Temperature Environments
- Low $R_{DS(ON)}$—Ensures Minimal On-State Losses
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies Just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Products
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DMPH4025SFVWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**
  https://www.diodes.com/quality/product-definitions/

Description and Applications

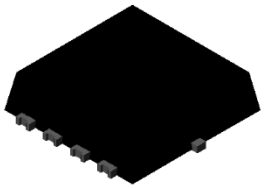
This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP, and is ideal for use in:

- Reverse-polarity protections
- Power-management functions
- DC-DC converters

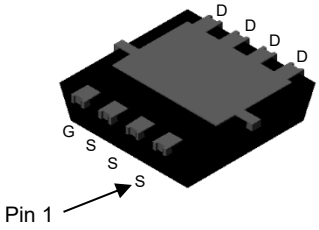
Mechanical Data

- Package: PowerDI3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.029 grams (Approximate)

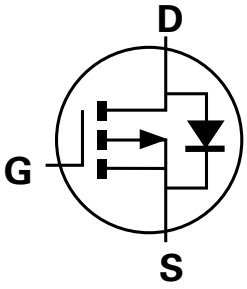
PowerDI3333-8/SWP (Type UX)



Top View



Bottom View



Equivalent Circuit

Ordering Information (Note 4)

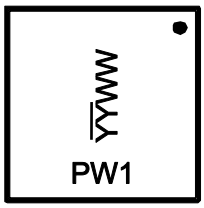
Orderable Part Number	Package	Packing	
		Qty.	Carrier
DMPH4025SFVWQ-7	PowerDI3333-8/SWP (Type UX)	2000	Tape & Reel
DMPH4025SFVWQ-13	PowerDI3333-8/SWP (Type UX)	3000	Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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Marking Information



PW1 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 26 = 2026)
WW = Week Code (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V_{DSS}	-40	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 5) V_{GS} = -10V	T_A = +25°C T_A = +70°C	I_D	-8.7 -7.3	A
	T_C = +25°C T_C = +70°C	I_D (Package Limited)	-40 -33	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I_{DM}	-80	A
Maximum Continuous Body Diode Forward Current		I_S	-3	A
Pulsed Source Current (10µs Pulse, Duty Cycle = 1%)		I_{SM}	-80	A
Avalanche Current, L = 0.3mH		I_{AS}	-23	A
Avalanche Energy, L = 0.3mH		E_{AS}	82	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T_A = +25°C	P_D	2.3	W
	T_C = +25°C		60	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	53	°C/W
Thermal Resistance, Junction to Case (Note 5)		$R_{\theta JC}$	2.5	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +175	°C

Note: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV_{DSS}	-40	—	—	V	V_{GS} = 0V, I_D = -250μA
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-1	μA	V_{DS} = -40V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	—	—	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS (Note 6)						
Gate Threshold Voltage	$V_{GS(TH)}$	-0.8	—	-1.8	V	V_{DS} = V_{GS}, I_D = -250μA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	18	25	mΩ	V_{GS} = -10V, I_D = -30A
		—	23	45		V_{GS} = -4.5V, I_D = -15A
Diode Forward Voltage	V_{SD}	—	—	-1	V	V_{GS} = 0V, I_S = -1A
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	C_{iss}	—	1918	—	pF	V_{DS} = -20V, V_{GS} = 0V f = 1MHz
Output Capacitance	C_{oss}	—	390	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	151	—	pF	
Gate Resistance	R_g	—	5.76	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge (V_{GS} = -4.5V)	Q_g	—	19.6	—	nC	V_{DS} = -20V, I_D = -3A
Total Gate Charge (V_{GS} = -10V)	Q_g	—	38.6	—	nC	
Gate-Source Charge	Q_{gs}	—	3.7	—	nC	
Gate-Drain Charge	Q_{gd}	—	7.3	—	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	4.8	—	ns	V_{DD} = -20V, V_{GS} = -10V I_D = -3A
Turn-On Rise Time	t_R	—	14.2	—	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	—	72.2	—	ns	
Turn-Off Fall Time	t_F	—	35.9	—	ns	

Notes: 6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to product testing.

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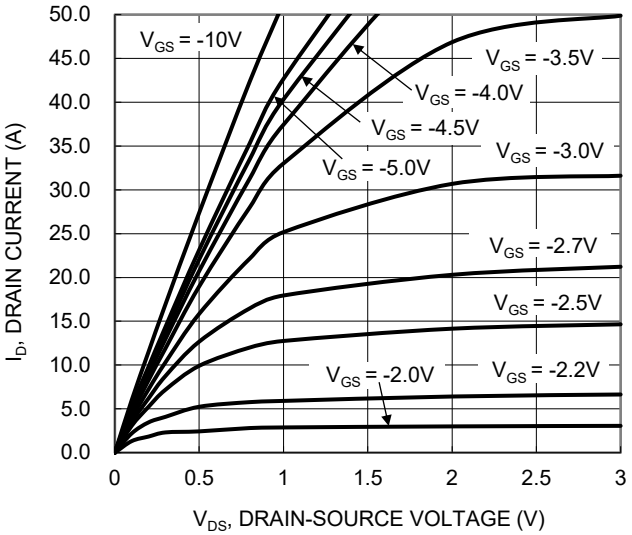


Figure 1. Typical Output Characteristic

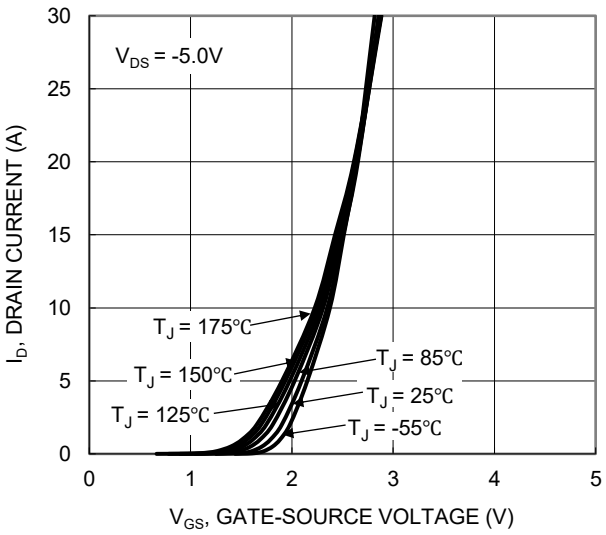


Figure 2. Typical Transfer Characteristic

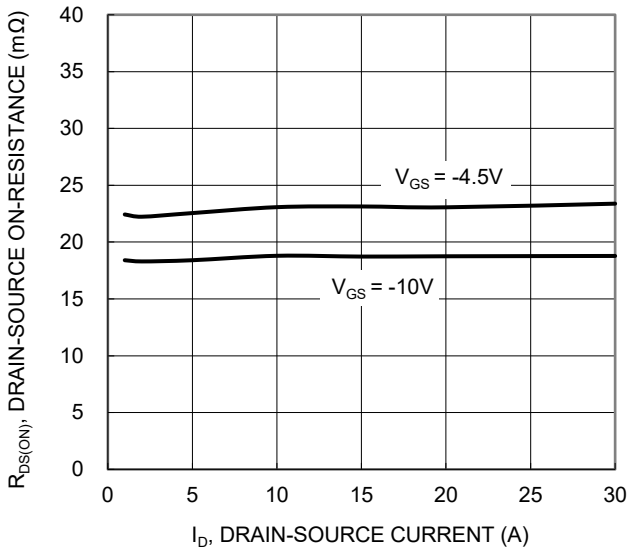


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

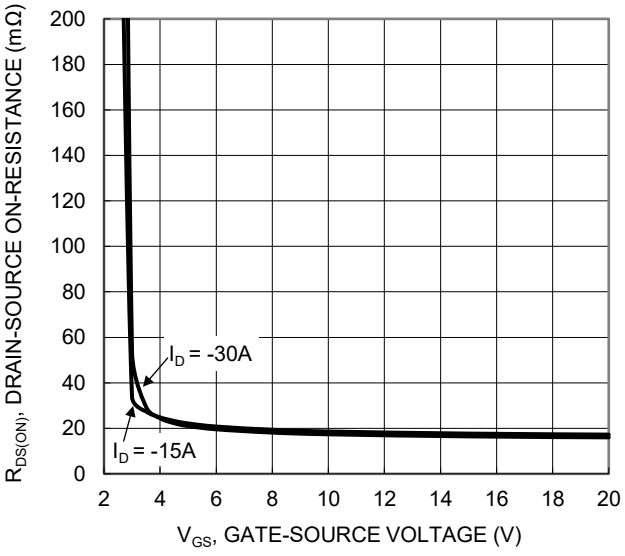


Figure 4. Typical Transfer Characteristic

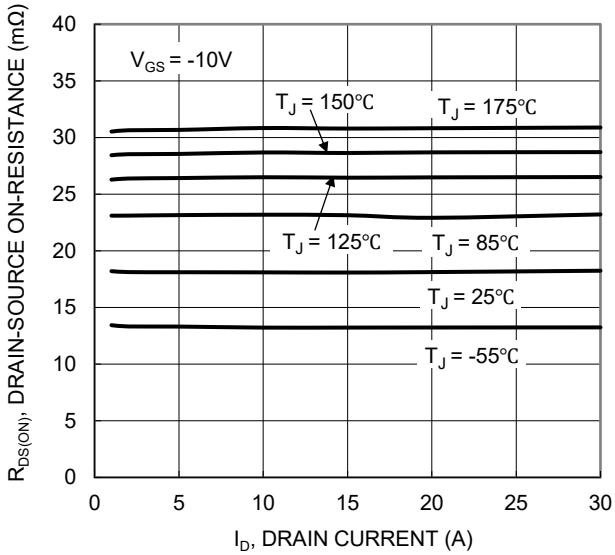


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

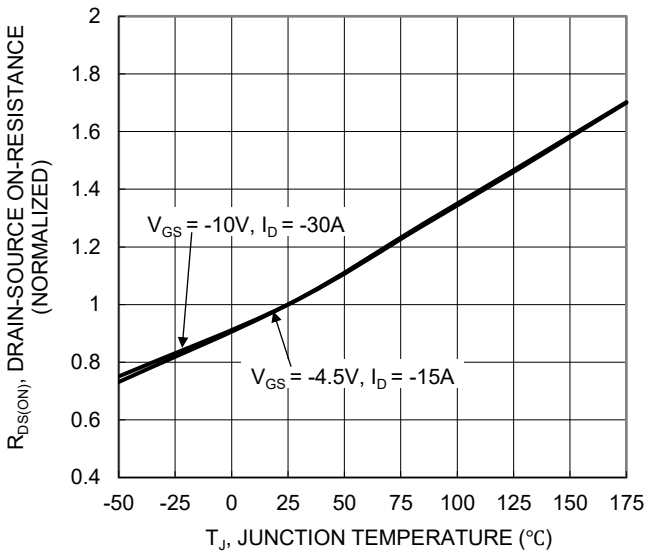


Figure 6. On-Resistance Variation with Temperature

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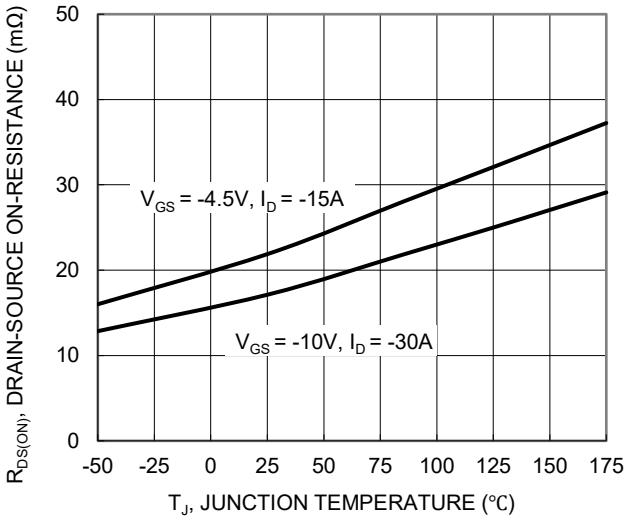


Figure 7. On-Resistance Variation with Temperature

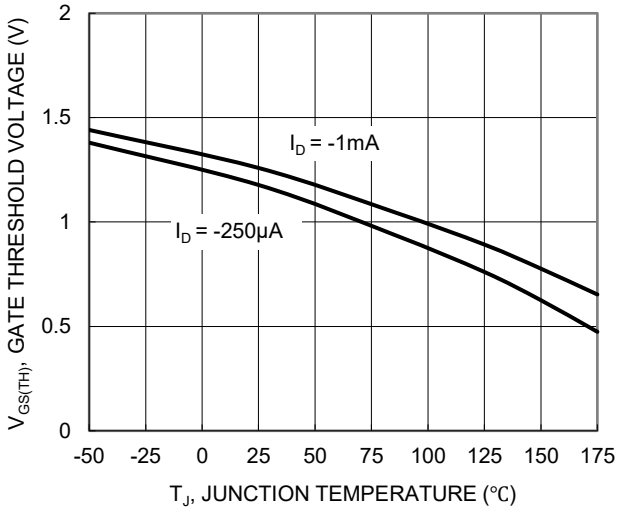


Figure 8. Gate Threshold Variation vs. Junction Temperature

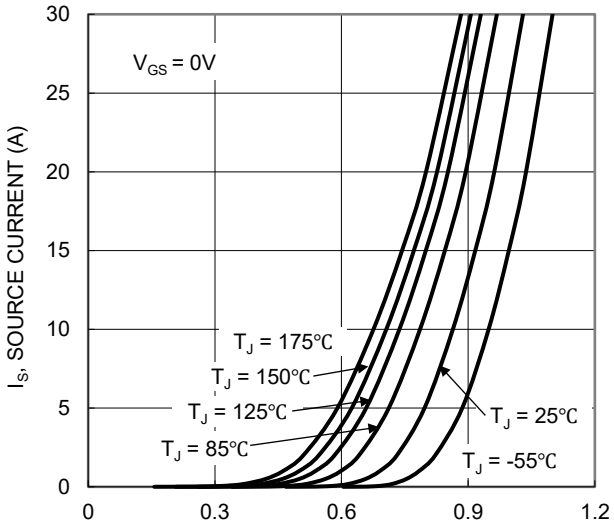


Figure 9. Diode Forward Voltage vs. Current

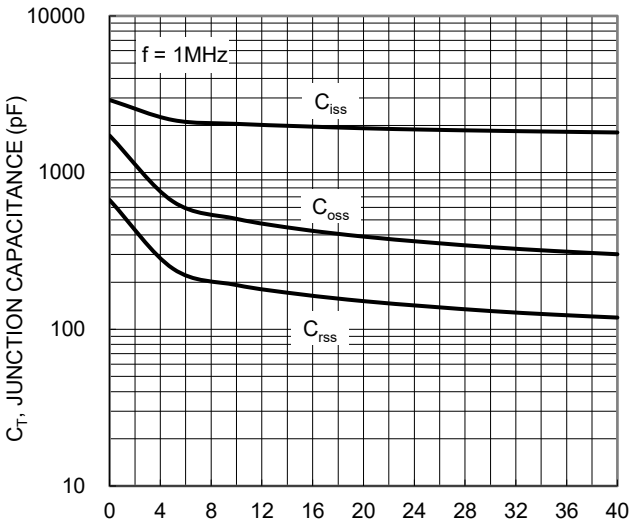


Figure 10. Typical Junction Capacitance

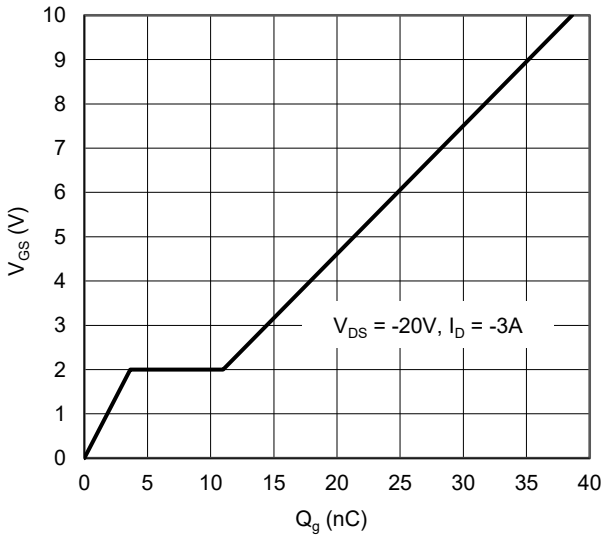


Figure 11. Gate Charge

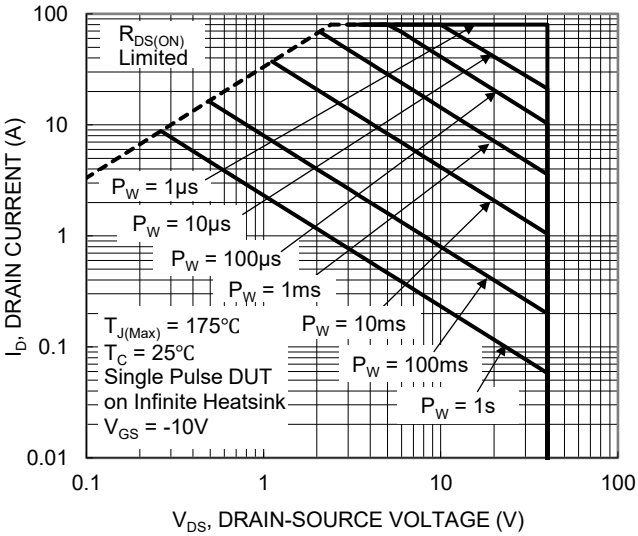


Figure 12. SOA, Safe Operation Area

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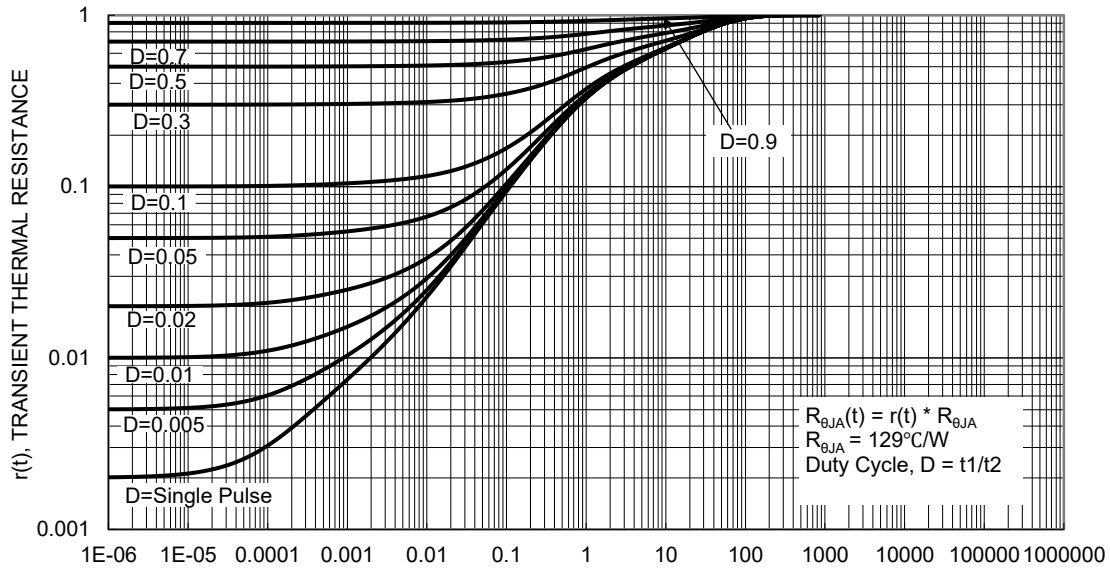


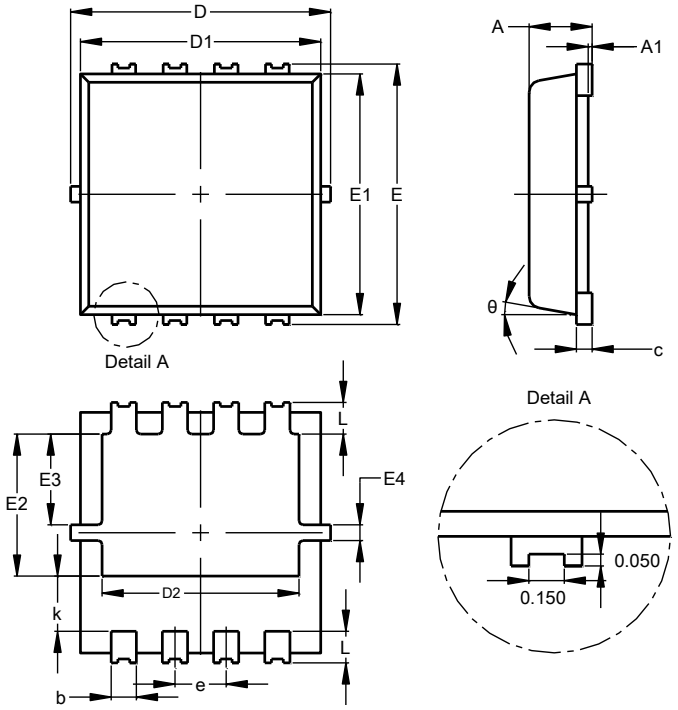
Figure 13. Transient Thermal Resistance

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)

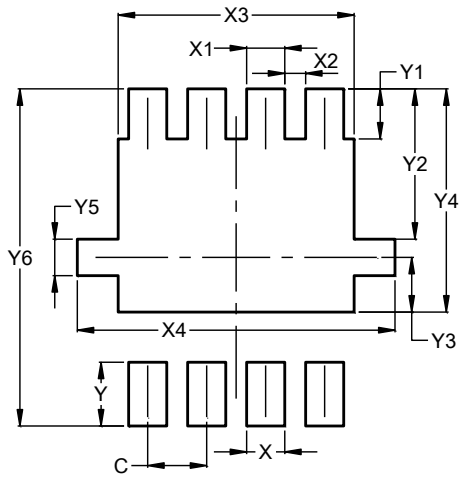


PowerDI3333-8/SWP (Type UX)			
Dim	**Min**	**Max**	**Typ**
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	2.30	2.70	2.50
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	–	–	0.65
k	0.50	0.90	0.70
L	0.30	0.50	0.40
θ	0°	12°	10°
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8/SWP (Type UX)



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.600
X4	3.500
Y	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700

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